

Data Sheet Issue:- 4

Rectifier Diode Types W2899MC420 to W2899MC480

Absolute Maximum Ratings

| | VOLTAGE RATINGS | MAXIMUM LIMITS | UNITS |
|------------------|---|-------------------|-------|
| V _{RRM} | Repetitive peak reverse voltage, (note 1) | 4200-4800 | V |
| V _{RSM} | Non-repetitive peak reverse voltage, (note 1) | 4300-4900 | V |

| | OTHER RATINGS | MAXIMUM LIMITS | UNITS |
|---------------------|---|----------------------|------------------|
| IF(AV)M | Maximum average forward current, Tsink=55°C, (note 2) | 2899 | А |
| IF(AV)M | Maximum average forward current. T _{sink} =100°C, (note 2) | 2030 | А |
| I _{F(AV)M} | Maximum average forward current. T _{sink} =100°C, (note 3) | 1214 | А |
| IF(RMS)M | Nominal RMS forward current, T _{sink} =25°C, (note 2) | 5312 | А |
| IF(d.c.) | D.C. forward current, T _{sink} =25°C, (note 4) | 4719 | А |
| I _{FSM} | Peak non-repetitive surge t _p =10ms, V _{rm} =60%V _{RRM} , (note 5) | 25.4 | kA |
| I _{FSM2} | Peak non-repetitive surge t _p =10ms, V _{rm} ≤10V, (note 5) | 28.0 | kA |
| l²t | $I^{2}t$ capacity for fusing t_{p} =10ms, V_{rm} =60% V_{RRM} , (note 5) | 3.23×10 ⁶ | A ² s |
| l ² t | $I^{2}t$ capacity for fusing t_{p} =10ms, V_{rm} ≤10V, (note 5) | 3.92×10 ⁶ | A ² s |
| T _{j op} | Operating temperature range | -40 to +160 | °C |
| T _{stg} | Storage temperature range | -55 to +160 | °C |

Notes:-

1) De-rating factor of 0.13% per °C is applicable for T_j below 25°C.

2) Double side cooled, single phase; 50Hz, 180° half-sinewave.

3) Cathode side cooled, single phase; 50Hz, 180° half-sinewave.

4) Double side cooled.

5) Half-sinewave, 160°C T_j initial.



Characteristics

| | PARAMETER | MIN. | TYP. | MAX. | TEST CONDITIONS (Note 1) | UNITS |
|-----------------|--|------|------|--------|---|-------|
| Vfm | Maximum peak forward voltage | - | - | 1.90 | IFM=4000A | V |
| Vfm | Maximum peak forward voltage | - | - | 2.90 | IFM=8600A | V |
| V _{T0} | Threshold voltage | - | - | 0.996 | | V |
| r⊤ | Slope resistance | - | - | 0.222 | | mΩ |
| Irrm | Peak reverse current | - | - | 50 | Rated V _{RRM} | mA |
| Qrr | Recovered charge | - | 7700 | - | | μC |
| Q _{ra} | Recovered charge, 50% Chord | - | 4900 | 5200 | I⊤ _M =1000A, t _p =1000µs, di/dt=10A/µs, | μC |
| Irm | Reverse recovery current | - | 205 | - | V _r =100V | |
| trr | Reverse recovery time, 50% chord | - | 48 | - | | μs |
| | | - | - | 0.0140 | Double side cooled | K/W |
| RthJK | Thermal resistance, junction to heatsink | - | - | 0.0265 | Anode side cooled | K/W |
| | | - | - | 0.0297 | Cathode side cooled | K/W |
| F | Mounting force | 25 | - | 31 | Note 2 | kN |
| Wt | Weight | | 530 | | | g |

Notes:-

1) Unless otherwise indicated $T_j=160^{\circ}C$.

2) For other clamp forces, please consult factory.



 $W_{AV} = \frac{\Delta T}{R_{th}}$ $\Delta T = T_{j \max} - T_{K}$

Notes on Ratings and Characteristics

1.0 Voltage Grade Table

| Voltage Grade | V _{RRM} V | V _{RSM} V | V _R DC V |
|---------------|-----------------------|-----------------------|------------------------|
| 42 | 4200 | 4300 | 2200 |
| 46 | 4600 | 4700 | 2400 |
| 48 | 4800 | 4900 | 2500 |

2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_j below 25°C.

4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

and:

5.0 Computer Modelling Parameters

5.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_{T0} + \sqrt{V_{T0}^{2} + 4 \cdot ff^{2} \cdot r_{T} \cdot W_{AV}}}{2 \cdot ff^{2} \cdot r_{T}}$$

Where $V_{T0}=0.996V$, $r_T=0.222m\Omega$,

 R_{th} = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

| Supplementary Thermal Impedance | | | | | | |
|---------------------------------|---------------|----------------|---------------|--------|--|--|
| Conduction Angle | 6 phase (60°) | 3 phase (120°) | ½ wave (180°) | d.c. | | |
| Square wave Double Side Cooled | 0.01665 | 0.01581 | 0.01516 | 0.0140 | | |
| Square wave Cathode Side Cooled | 0.03217 | 0.03147 | 0.03090 | 0.0297 | | |
| Sine wave Double Side Cooled | 0.01612 | 0.01531 | 0.01436 | | | |
| Sine wave Cathode Side Cooled | 0.03174 | 0.03105 | 0.03022 | | | |

| Form Factors | | | | | | |
|---|-------|-------|-------|---|--|--|
| Conduction Angle6 phase (60°)3 phase (120°)½ wave (180°)d.c | | | | | | |
| Square wave | 2.449 | 1.732 | 1.414 | 1 | | |
| Sine wave | 2.778 | 1.879 | 1.57 | | | |



5.2 Calculating VF using ABCD Coefficients

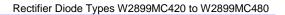
The on-state characteristic I_F vs. V_F, on page 6 is represented in two ways;

- (i) the well-established V_{T0} and r_T tangent used for rating purposes and
- (ii) a set of constants A, B, C, D, forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

| 25°C Coefficients | | 160°C Coefficients | |
|-------------------|---------------------------|--------------------|---------------------------|
| Α | 0.827663843 | А | 0.426801943 |
| В | 0.01267808 | В | 0.05611887 |
| С | 1.039088×10 ⁻⁴ | С | 1.811695×10 ⁻⁴ |
| D | 5.603232×10 ⁻³ | D | 4.475688×10 ⁻³ |





5.3 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left(1 - e^{\frac{-t}{\tau_p}}\right)$$

Where p = 1 to *n*, *n* is the number of terms in the series and:

- t = Duration of heating pulse in seconds.
- $r_t =$ Thermal resistance at time t.
- r_p = Amplitude of p_{th} term.
- τ_p = Time Constant of r_{th} term.

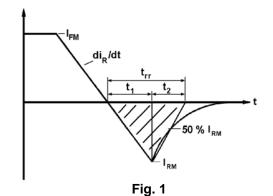
The coefficients for this device are shown in the tables below:

| D.C. Double Side Cooled | | | | | | |
|-------------------------|---------------------------|---------------------------|---------------------------|---------------------------|--|--|
| Term | Term 1 2 3 4 | | | | | |
| r _p | 8.594785×10 ⁻³ | 3.308247×10 ⁻³ | 1.039072×10 ⁻³ | 7.916582×10 ⁻⁴ | | |
| τρ | 0.7185764 | 0.09970181 | 0.02165834 | 5.266433×10 ⁻³ | | |

| | D.C. Cathode Side Cooled | | | | | | |
|----------------|--------------------------|---------------------------|---------------------------|--|--|--|--|
| Term | 1 | 2 | 3 | | | | |
| r _p | 0.02196926 | 5.845724×10 ⁻³ | 1.904897×10 ⁻³ | | | | |
| τρ | 4.127141 | 0.1629998 | 8.832583×10 ⁻³ | | | | |

6.0 Reverse recovery ratings

(i) $Q_{ra}\xspace$ is based on 50% $I_{rm}\xspace$ chord as shown in Fig. 1



(ii) Q_{rr} is based on a 150µs integration time i.e.

$$Q_{rr} = \int_{0}^{150\,\mu s} i_{rr}.dt$$

(iii)

K Factor =
$$\frac{t_1}{t_2}$$



<u>Curves</u>

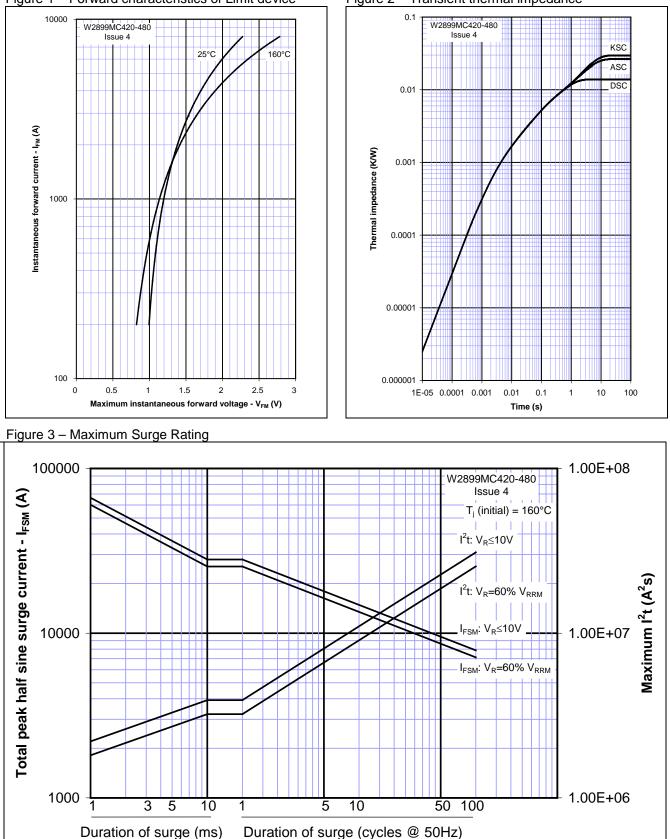
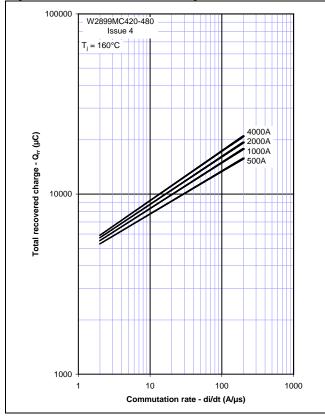


Figure 1 – Forward characteristics of Limit device

Figure 2 – Transient thermal impedance



Figure 4 – Total recovered charge, Qrr





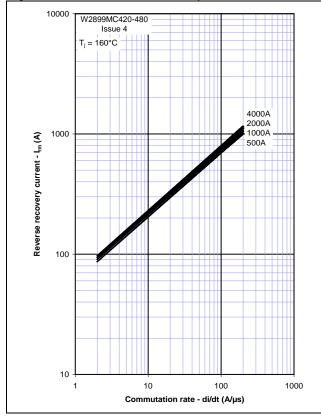
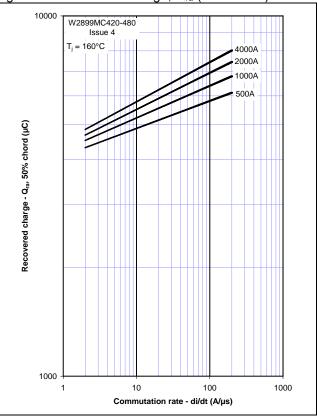
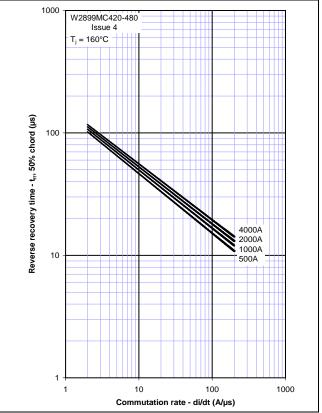


Figure 5 – Recovered charge, Q_{ra} (50% chord)









10000 W2899MC420-480 Issue 4 9000 3ø 60 8000 7000 Maximum Forward Dissipation (W) 6000 5000 4000 3000 2000 1000 0 1000 2000 3000 4000 5000 6000 0

Figure 8 – Forward current vs. Power dissipation – Double Side Cooled

Figure 10 – Forward current vs. Power dissipation – Cathode Side Cooled

Mean Forward Current (A) (Whole cycle averaged)

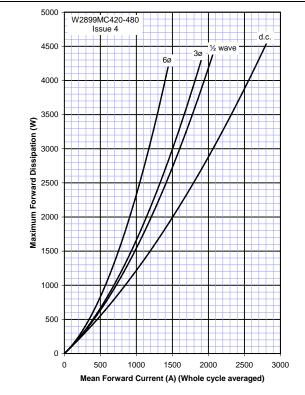


Figure 9 – Forward current vs. Heatsink temperature – Double Side Cooled

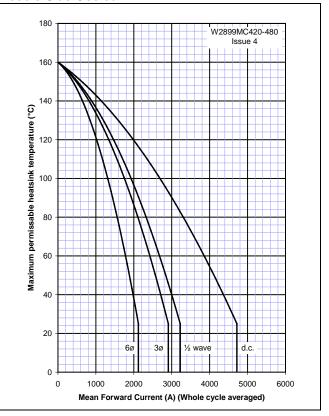
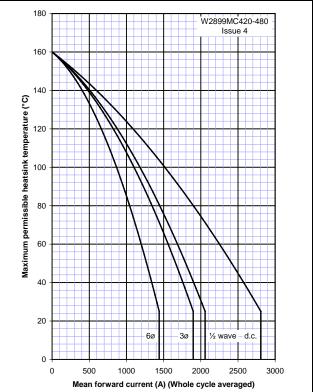
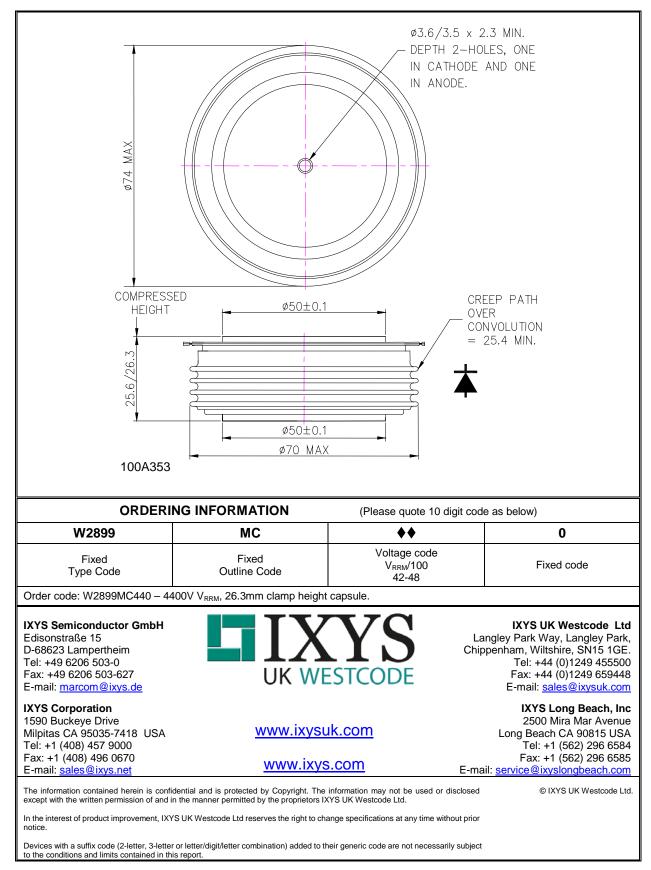


Figure 11 – Forward current vs. Heatsink temperature – Cathode Side Cooled





Outline Drawing & Ordering Information





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